

Schottky Dual Diode

PBYL1520CTB

20V / 15A

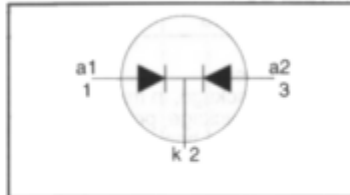
DATASHEET

OEM – Philips

Source: Philips Databook 1999

**Rectifier diodes
Schottky barrier**
PBYL1525CT, PBYL1525CTB series
FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL

QUICK REFERENCE DATA

$$V_R = 20 \text{ V} / 25 \text{ V}$$

$$I_{O(AV)} = 15 \text{ A}$$

$$V_F \leq 0.42 \text{ V}$$

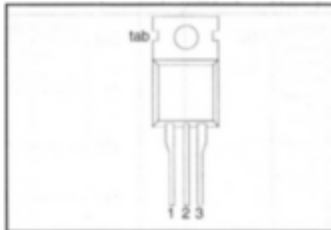
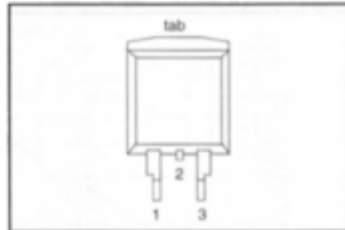
GENERAL DESCRIPTION

Dual schottky rectifier diodes intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYL1525CT series is supplied in the SOT78 (TO220AB) conventional leaded package.
The PBYL1525CTB series is supplied in the SOT404 surface mounting package.

PINNING

PIN	DESCRIPTION
1	gate
2	drain ¹
3	source
tab	drain

SOT78 (TO220AB)

SOT404

LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
				20CT 20CTB	25CT 25CTB	
V_{RRM}	Peak repetitive reverse voltage		-	20	25	V
V_{RWM}	Working peak reverse voltage		-	20	25	V
V_R	Continuous reverse voltage	$T_{mb} \leq 107 \text{ }^\circ\text{C}$	-	20	25	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting)	square wave; $\delta = 0.5$; $T_{mb} \leq 127 \text{ }^\circ\text{C}$	-	15		A
I_{FRM}	Repetitive peak forward current per diode	square wave; $\delta = 0.5$; $T_{mb} \leq 127 \text{ }^\circ\text{C}$	-	15		A
I_{FSM}	Non-repetitive peak forward current per diode	$t = 10 \text{ ms}$	-	90		A
		$t = 8.3 \text{ ms}$	-	100		A
I_{RRM}	Peak repetitive reverse surge current per diode	sinusoidal; $T_j = 125 \text{ }^\circ\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by T_{jmax}	-	1		A
T_j	Operating junction temperature		-	150		$^\circ\text{C}$
T_{stg}	Storage temperature		-65	175		$^\circ\text{C}$

1. It is not possible to make connection to pin 2 of the SOT404 package.

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R_{m-j-mb}	Thermal resistance junction to mounting base	per diode both diodes	-	-	3	K/W
R_{m-j-a}	Thermal resistance junction to ambient	SOT78 package, in free air	-	60	-	K/W
		SOT404 package, pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

ELECTRICAL CHARACTERISTICS

All characteristics are per diode at $T_j = 25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	Forward voltage	$I_F = 7.5\text{ A}; T_j = 150^\circ\text{C}$	-	0.37	0.42	V
		$I_F = 7.5\text{ A}; T_j = 125^\circ\text{C}$	-	0.39	0.45	V
		$I_F = 15\text{ A}; T_j = 125^\circ\text{C}$	-	0.57	0.61	V
		$I_F = 15\text{ A}$	-	0.59	0.64	V
I_R	Reverse current	$V_R = V_{RWM}$	-	0.2	5	mA
		$V_R = V_{RWM}; T_j = 100^\circ\text{C}$	-	10	20	mA
C_j	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}; T_j = 25^\circ\text{C to } 125^\circ\text{C}$	-	350	-	pF

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